

55 GHz Octal-site Wafer Test Probecard for 5G mmWave devices

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TestConX 2022

High Speed

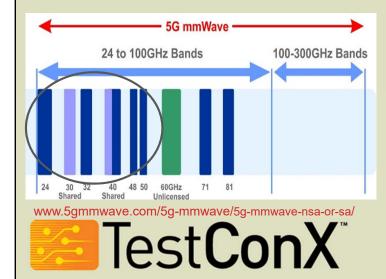
Intro: 5G mmWave Drivers

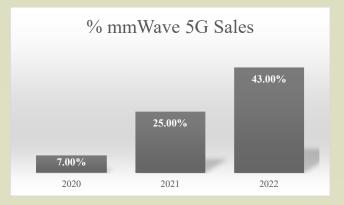
- Demand
 - Urban area capacity, fixed wireless broadband (FWA), video streaming, AR/VR, Critical IOT such as autonomous vehicles and mobile healthcare
- Frequency
 - 5G FR2 (frequency range 2) (24.25GHz to 52.6GHz)
 - Bandwidth up to 3.4GHz

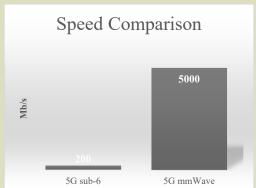
- 5G Comparison:
 - 5G sub-6Ghz 200Mb/s
 - 5G mmWave 5Gb/s



- Percentage mmWave sales
 - 43% phones by 2022





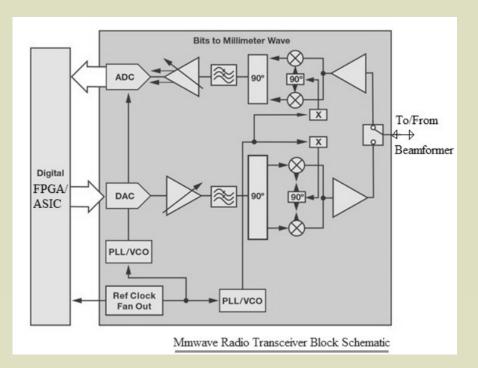


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5G transceivers

- mmWave 5G radio
 - Transmitter
 - DAC
 - Power Amplifier
 - Up-conversion
 - Receiver
 - Low Noise Amplifier
 - Down-conversion
 - ADC
- Possible Vendors
 - Anokiwave, ADI, Nokia, Qualcomm, Ericsson, etc.



Mmwave 5G Radio | 5G mmwave transceiver manufacturers or vendors (rfwireless-world.com)



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Introduction – RF Probing Challenges

- General probing challenges
 - Planarity
 - Overdrive
 - Maintenance
 - Initial Cost
 - COT
 - Throughput
 - Yield
 - Routing
 - Temperature

- RF probe card challenges
 - Higher Initial Cost
 - Exotic Space transformers
 - Multisite limitations
 - Loss
 - Reflections
 - Repeatability
 - Tester resource Limitations
 - Components, connectors, switching, cabling



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Wafer probe Objectives / Goals

- Mechanical targets
 - 600+ i/o die
 - 150 um pitch
 - Octal Site Probecard
 - ~5000 contacts
 - <50 um planarity</p>
 - >100 RF connectors/cables
 - >100 01005 components (capacitors, resistors)
 - >80 RF mmWave switches
 - Full probecard including stiffener, cabling, docking, RF brackets, etc.

- Electrical targets
 - 55 GHz to tester
 - 55 Ghz loopback
 - 44 GHz switching
 - Low impedance power supplies
 - 10 dB max return loss
 - 50 ohm impedance match
 - Simulated and measured full path from tester to DUT for calibration and de-embedding



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Methods/Materials

- cRacer Probehead
 - 3mm test height spring probe, 150 um pitch, 6g, 150 um overdrive (DUT side)
 - Metal frame, stiffener, 8 site MA
 - Simulated and optimized signal integrity, bowing/stress analysis
 - Measured life cycle, cRes, CCC, RF, planarity, force
- Direct Attach PCB
 - Fanout in PCB (no space transformer/MLO/MLC required)
 - 100+ RF channels (5 GHz-55 GHz RF paths)
 - Simulated signal integrity (HFSS, SI Wave)
 - DUT side: surface, internal traces
 - Tester side: surface, internal traces
 - 25 Power supplies
 - Simulated IR drop and impedance (SI Wave) all 8 sites

- Connectors/Cabling
 - SMPM connectors, Cabling
 - Simulated launch geometries
- Switching
 - 10-44 GHz SP4T switches
 - Simulated launch geometries

Components

- 01005 capacitors and resistors for signal integrity and space savings
- Simulated footprints

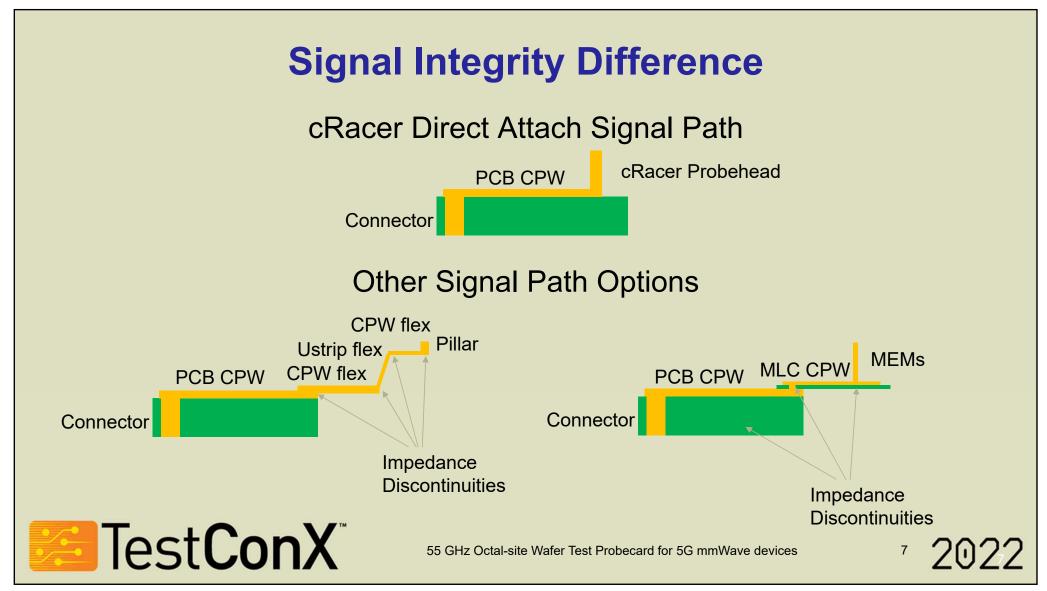
Simulation and Measurement equipment

- Ansys CFD, HFSS, SI Wave
- PCA (Cohu FReD machine)
- VNA (67GHz Keysight)
- Cycler (Kita)



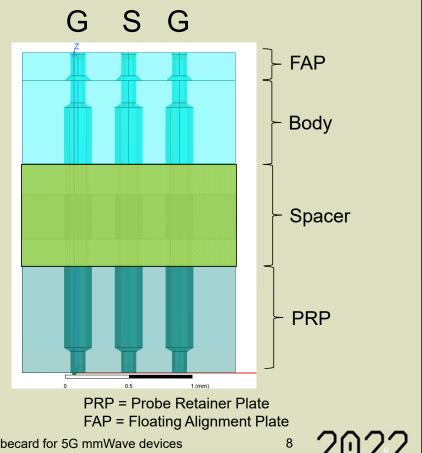


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cRacer Optimization Process (Patent Pending)

- Select pin based on required pitch and tip profile (150 um crown tip in this case)
- Select contactor materials for PRP, Spacer, Body and FAP to provide required mechanical strength and dielectric performance
- Simulate RF performance in GSG or GSSG configuration
- Tune performance by matching to required impedance (typically 50 Ohms) across bandwidth of interest

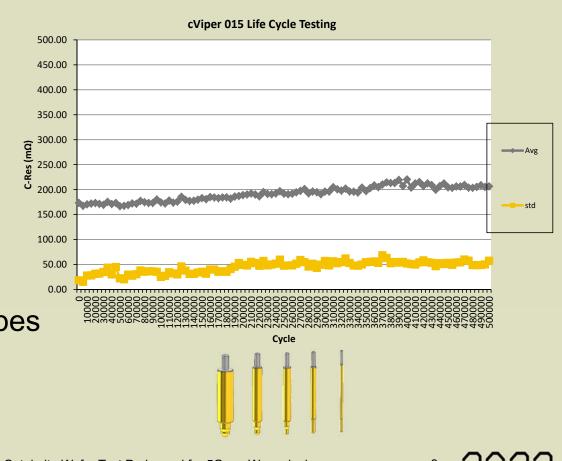




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Radial Probe cRes Optimization

- Expertise leveraged for performance
- Back to the Basics
 - Low and consistent cRes
 - Lot-to-lot stability
 - Long lifetime
 - Optimized "Guts"
- Standardized Recipe for probes and cross sections

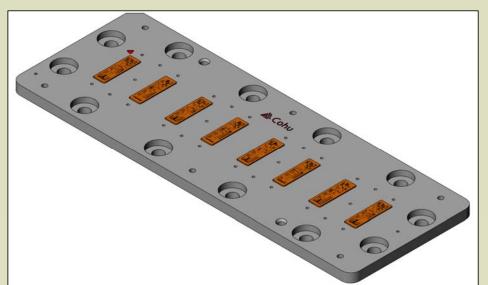


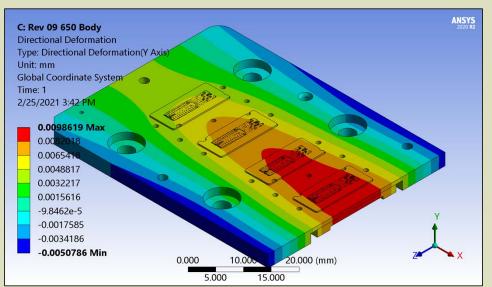


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Bowing Simulation – Rev 04

- Predict the bowing deflection due to probe preload that can be expected from Probehead using Ansys simulation
- Max Y-Directional Deformation: 10.3 μm





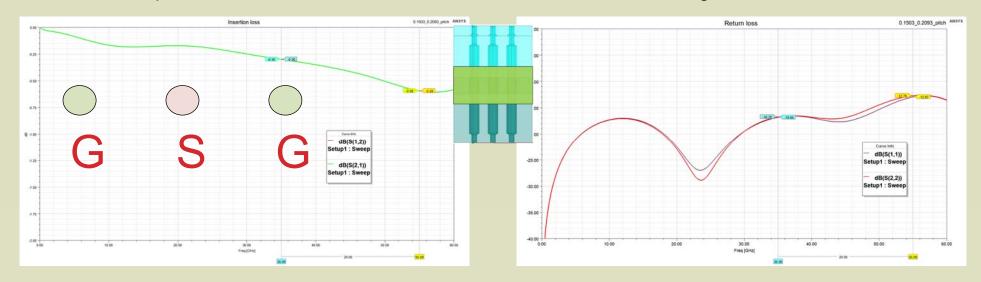


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cRacer Probehead Simulated Insertion Loss

- Predict the insertion loss and return loss expected from Probehead using Ansys simulation out to 55 GHz
 - Great performance with <1 dB Insertion loss, <-12 dB return loss through 60 GHz



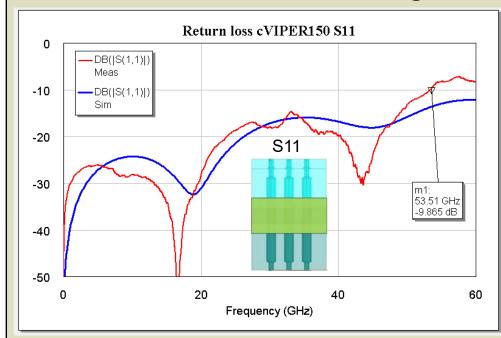


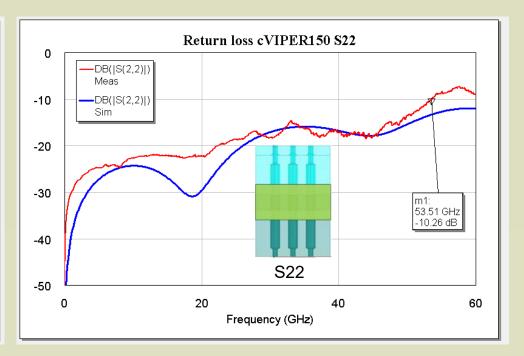
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cRacer 150 Return loss Correlation

- cRacer150 GSG Probehead RF Measurement to RF Simulation correlation
 - Great correlation between simulation and measurement
 - simulation -12 dB, measurement -10 dB @ 53 GHz

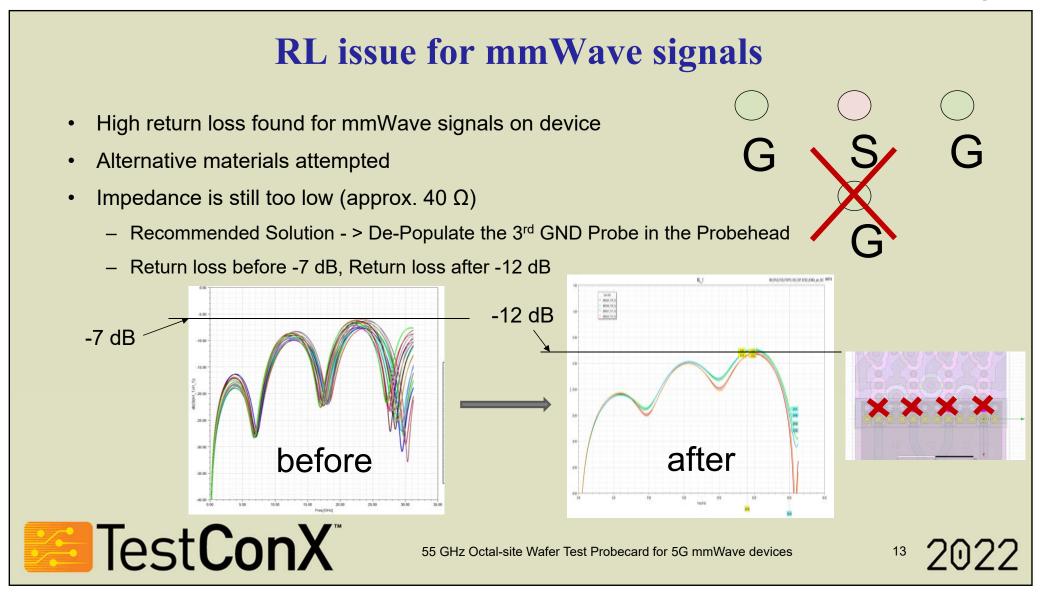


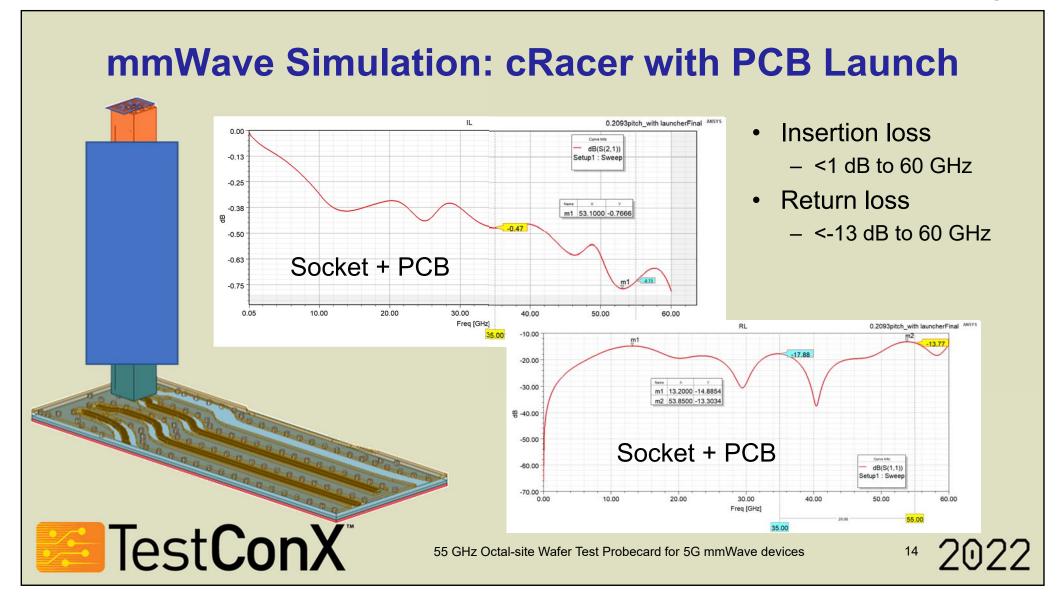




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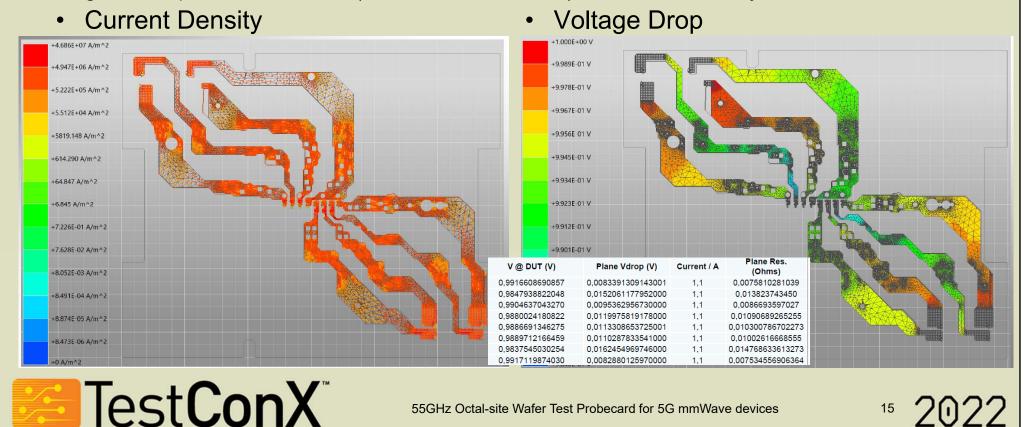
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DC Voltage Drop Simulations (1V supply)

Target IR drop less than 24 mV (16 mV Max simulated) achieved thru Ansys SI Wave simulation



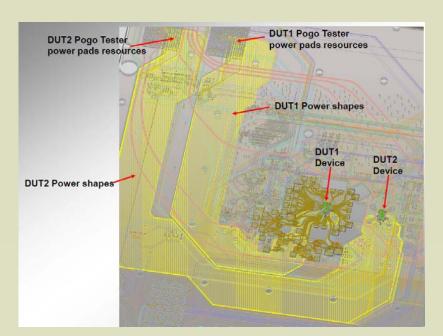
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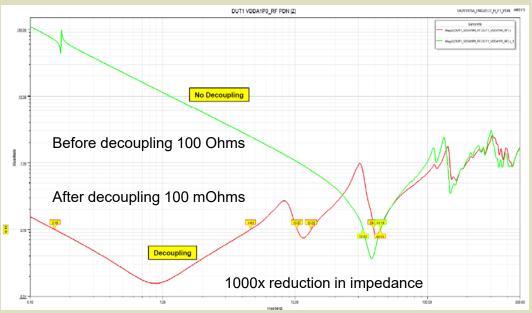
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Power Supply Impedance Modeling

• Site 1, 2 power supply configuration

Impedance improvement after Decoupling







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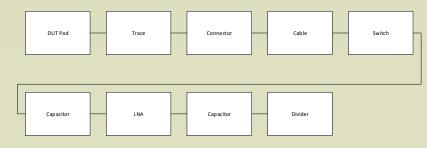
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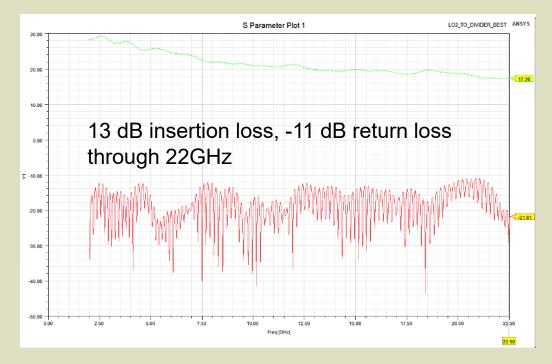
LO Full Path Simulation example

Simulation Includes:

- DUT pad (HFSS), CPW trace (W-element), connector(HFSS), coaxial cable(2D), bias-T (sparam), switch (s-param), bypass caps (sparam), LNA (HFSS, s-param), divider (HFSS, s-param)
- Used for de-embedding in test program prior to full path s-parameter measurements

Schematic





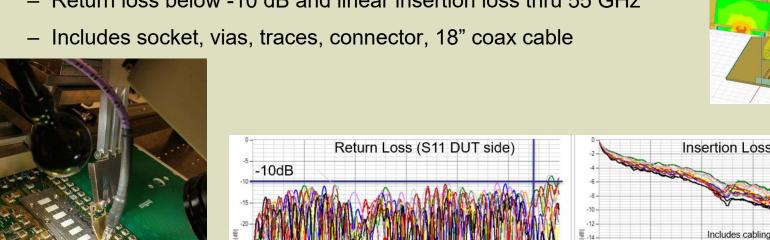


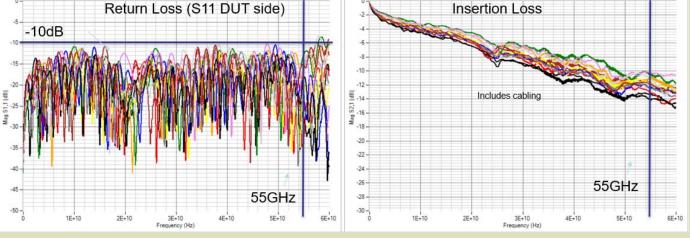
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Full Path S-parameter measurement to 55GHz

- Tester to DUT full path loss (12x 55 GHz paths)
 - Return loss below -10 dB and linear insertion loss thru 55 GHz



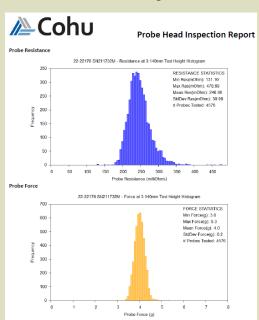




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Probehead Inspection

- Resistance Average: 250 mOhm
- Resistance STD: 30 mOhm
- Force Average: 4 g
- Force STD: 0.2 g



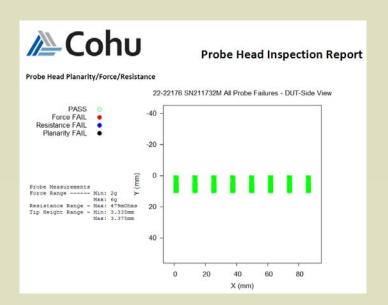
First touch average: 3.36 mm

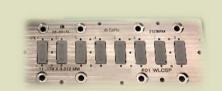
First touch STD: 7 um

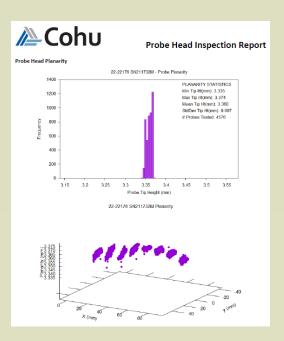
• Min tip height: 3.335 mm

Max tip height: 3.374 mm

Coplanarity: 41 um









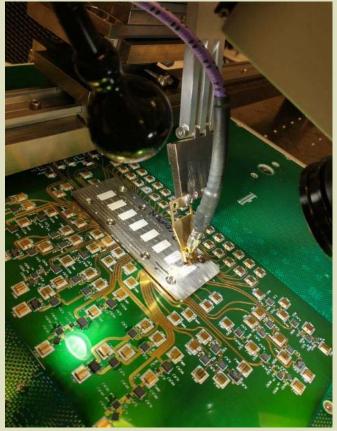
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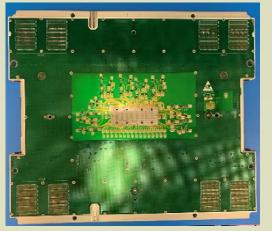
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cRacer 55 GHz Octal-Site Direct Attach Probe Card









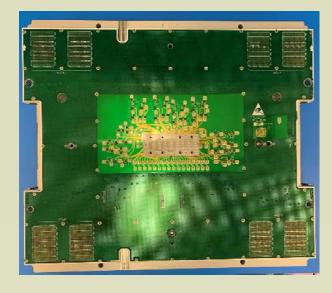




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Discussion of Results

- Advantages
 - 8+ site capable mmWave Vertical Probecard Solution
 - Traditional Spring Probe Technology
 - Direct Attach (no MLO/MLC)
 - Field maintainable
 - Lower Cost of Test
- Challenges
 - Significant Engineering Design effort
 - Limited real-estate limits optimal RF Routing
 - PCB registration and lamination
 - High BOM count/cost and assembly complexity
 - Long-leadtime mmWave components





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Summary / Conclusion

- Proven performance of a cRacer probecard
 - Multisite (8+) spring probe probecard for 150 um pitch applications
 - RF performance through 55 GHz
 - Design, simulation, prototype and production builds completed
 - Platform developed for generations of mmWave die and package test
- Turnkey Production Probe solution
 - Mechanical/electrical design, supply-chain management, assembly and test coordination, and global logistics management
 - Product and processes developed for high-volume probecard applications



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Follow-On Work

- Redesign for alternative impedance profiles
 - Printed impedance transformers, High-Power cRacer socket
- Optimize cable lengths and routing for lower loss
 - Initial design used 19" cables for simplicity
 - Optimized design can cut half the loss and half the length
- Add fiducial alignment for finer pitches
- Simplify test for high-volume orders
 - Automated PCA and RF test Stations to increase capacity by 10x+





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Thanks to:

- Synergie CAD
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- Cohu
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 - Peter Cockburn (Senior Product Marketing Manager)
 - Anne Krantz (Product Development Engineering Manager)



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